

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Present Application:

Applicants : Chih-Chen Cho and Zhongze Wang Attorney Docket No. : 500982.02 (30016/US/2)

Filed : Concurrently herewith Customer No. : 27,076

Title : METHODS FOR MAKING SEMICONDUCTOR STRUCTURES HAVING HIGH-SPEED
AREAS AND HIGH-DENSITY AREAS

Prior Application:

Examiner : Toniae M. Thomas

Art Unit : 2822

Serial No. : 09/945,077

PRELIMINARY AMENDMENT

Mail Stop Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks begin on page 13 of this paper.